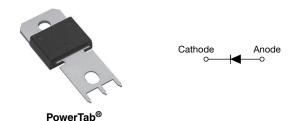
## **VS-150EBU02HF4**

**Vishay Semiconductors** 

# Ultrafast Soft Recovery Diode, 150 A FRED Pt<sup>®</sup>



www.vishay.com

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	150 A				
V <sub>R</sub>	200 V				
V <sub>F</sub> at I <sub>F</sub>	0.77 V				
t <sub>rr</sub> (typ.)	See recovery table				
T <sub>J</sub> max.	175 °C				
Package	PowerTab <sup>®</sup>				
Circuit configuration	Single				

### **FEATURES**

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- · Screw mounting only
- AEC-Q101 gualified
- PowerTab<sup>®</sup> package
- COMPLIANT • Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **BENEFITS**

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

### **DESCRIPTION/APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V <sub>R</sub>		200	V		
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 116 °C	150			
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	1600	А		
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	380			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.		UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-	
Forward voltage	VF	I <sub>F</sub> = 150 A	-	0.94	1.10	V
Forward voltage	۷F	I <sub>F</sub> = 150 A, T <sub>J</sub> = 175 °C	-	0.77	0.88	
		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50	μA
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	2	mA
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	180	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	3.5	-	nH

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VS-150EBU02HF4



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DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	+	T <sub>J</sub> = 25 °C		-	48	-	20
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 150 A V <sub>R</sub> = 160 V dI <sub>F</sub> /dt = 200 A/μs	-	88	-	ns
Peak recovery current		T <sub>J</sub> = 25 °C		-	5	-	A
Feak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	12	-	
Reverse recovery charge Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	120	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	520	-	no

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.35	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.2	-	r∨ vv
Weight			-	-	5.02	g
weight			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab <sup>®</sup>	150EBU02H			

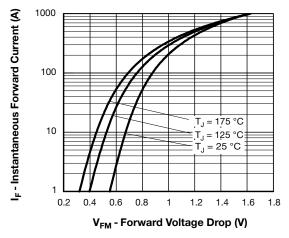
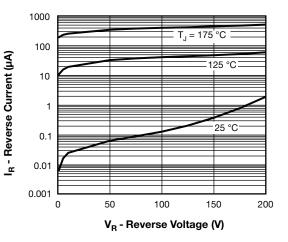
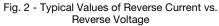


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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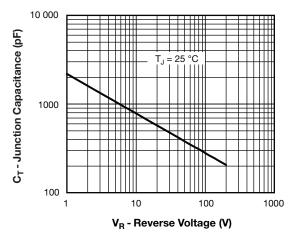


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

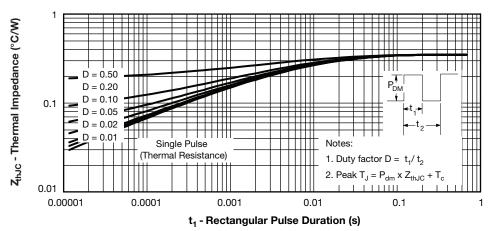
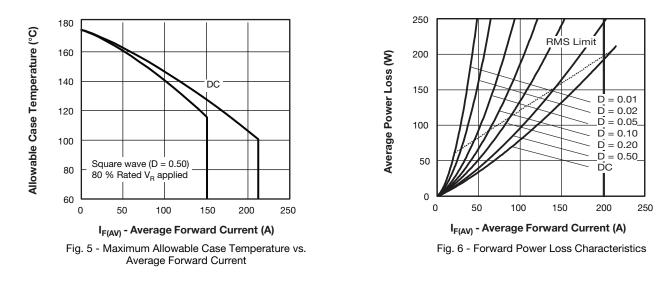


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics



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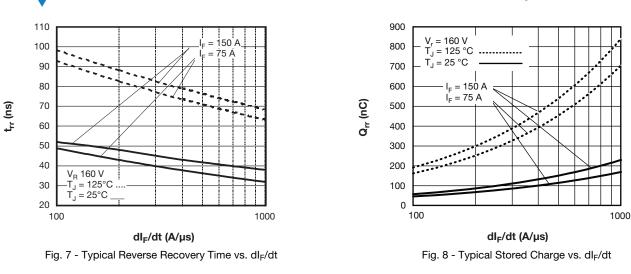
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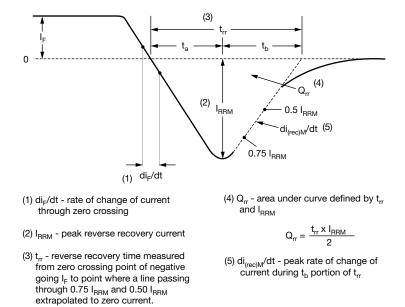


Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

Device code	VS-	150	Е	в	U	02	Н	F4
	1	2	3	4	5	6	7	8
	<b>1</b> ·	- Visł	nay Sem	niconduc	ctors pro	duct		
	2	Cur	rent rati	ng (150	= 150 A	.)		
	3.	Sing	gle diod	е				
	4	· Pov	verTab®	)				
	5	Ultr	afast ree	covery				
	6	- Volt	tage rati	ng (02 =	= 200 V)			
	7.	• H=	AEC-Q	101 qua	lified			
	8	• F4 :	= RoHS	-complia	ant and t	otally le	ad (Pb)-	free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-150EBU02HF4	25	375	Antistatic plastic tube			

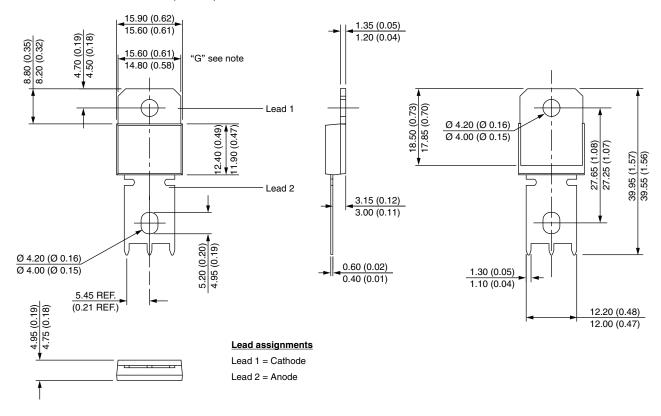
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467				
Application note	www.vishay.com/doc?95179				
SPICE model	www.vishay.com/doc?96503				



**Vishay Semiconductors** 

**PowerTab**<sup>®</sup>

### **DIMENSIONS** in millimeters (inches)



#### Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only

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